

600V HIGH- AND LOW-SIDE GATE DRIVER

Features

- High side fully operational to +600V
- Floating channel designed for bootstrap operation
- Output source/sink current capability 2.5A
- Common-Mode dV/dt noise canceling circuit
- Gate drive supply range from 10V to 20V
- Under-voltage lockout for both channels
- 3.3V logic compatible
- Separate logic supply range from 3.3V to 20V
- Logic and power ground ±5V offset
- CMOS Schmitt-triggered inputs with pull-down
- Cycle by cycle edge-triggered shutdown logic
- Outputs in phase with inputs
- Matched propagation delay for both channels

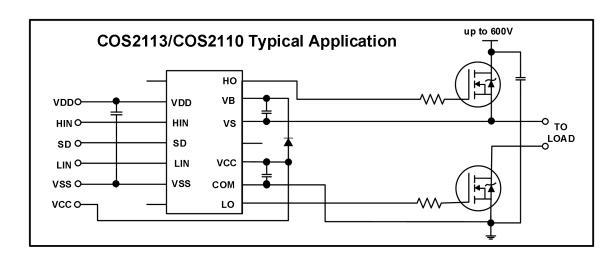
Applications

- Motor Drivers
- Full/Half Bridge Converters
- Two Switch forward Converter

General Description

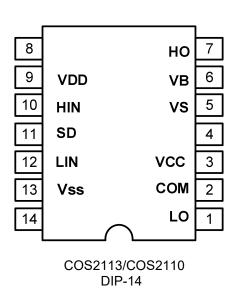
The COS2113/COS2110 are high voltage and high speed power MOSFET and IGBT drivers with independent high-side and low-side referenced output channels. The output drivers feature a high pulse current buffer stage designed for minimum driver cross-conduction. Propagation delays are matched to simplify use in high frequency applications. The floating channel can be used to drive an N-channel power MOSFET or IGBT in the high-side configuration which operates up to 600V. The of COS2113/COS2110 Logic inputs compatible with standard CMOS or TTL output, down to 3.3V logic. COS2113/COS2110 are available in Green wide SOP16, and DIP14 Packages.

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1. Pin Configuration and Functions



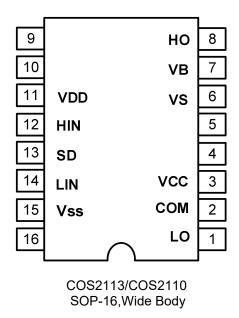


Figure 1. Pin Diagram

Pin Description

Name	Pin No. (DIP14)	Pin No. (SOP16)	Description		
VDD	9	11	Logic supply		
HIN	10	12	Logic input for high-side gate driver output (HO), in phase		
SD	11	13	Logic input for shutdown		
LIN	12	14	Logic input for low-side gate driver output (LO), in phase		
VSS	13	15	Logic ground		
VB	6	7	High-side floating supply		
НО	7	8	High-side gate drive output		
VS	5	6	High-side floating supply return		
VCC	3	3	Low-side supply		
LO	1	1	Low-side gate drive output		
COM	2	2	Low-side return		



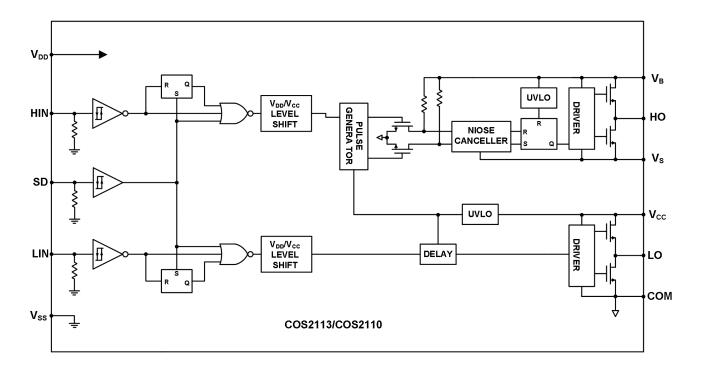


Figure 2. Functional Block Diagram

2. Product Specification

2.1 Absolute Maximum Ratings (1)

Parameter	Symbol	Min	Max	Unit
High-side floating supply voltage	VB	-0.3	620	V
High-side floating supply offset voltage	VS	VB - 20	VB +0.3	V
High-side floating output voltage	VHO	VS - 0.3	VB + 0.3	V
Low-side fixed supply voltage	VCC	-0.3	20	V
Low-side output voltage	VLO	-0.3	VCC + 0.3	V
Logic supply voltage	VDD	-0.3	VSS +20	V
Logic supply offset voltage	VSS	VCC-20	VSS +0.3	V
Logic input voltage (HIN, LIN, SD)	VIN	VSS-0.3	VDD +0.3	V
Allowable offset supply voltage transient	dVs/dt	-	50	V/ns
Junction temperature	TJ	-	150	°C
Storage temperature	Ts	- 55	150	°C
Lead temperature (soldering, 10 seconds)	TL	-	300	°C

⁽¹⁾ Stresses exceeding the absolute maximum ratings may damage the device. The device may not function or be operable above the recommended operating conditions and stressing the parts to these levels is not recommended. In addition, extended exposure to stresses above the recommended operating conditions may affect device reliability. The absolute maximum ratings are stress ratings only.



2.2 Thermal Data

Parameter	Rating	Unit
Package Thermal Resistance	100 (WSOP16) 75 (DIP14)	°C/W

2.3 Recommended Operating Conditions

Parameter	Symbol	Min	Max	Unit
High-side floating supply voltage	VB	VS+10	VS+20	
Low-side fixed supply voltage	VCC	10	20	
Logic supply voltage	VDD	VSS+3	VSS+20	V
Logic supply offset voltage	VSS	-5	5	
Logic input voltage (HIN, LIN, SD)	VIN	VSS	VDD	
Operation temperature	TA	-40	125	°C

2.4 Electrical Characteristics

VBIAS (VCC, VBS, VDD) = 15 V, T_A = 25 °C , C_L =1000pF and VSS = COM, unless otherwise specified.

Parameter	Symbol	Conditions	Min.	Тур.	Max.	Unit		
INPUT								
Input signal high threshold	V _{IH}		2.5	-		V		
Input signal low threshold	VIL			-	0.8	V		
Logic "1" input bias current	I _{IN+}	V _{IN} = 5V		10	20	μA		
Logic "0" input bias current	I _{IN-}	V _{IN} = 0 V		-	2.0	μA		
OUTPUT	OUTPUT							
High level output voltage, VBIAS- VO	Vон	lo=20mA		-	1.4	V		
Low level output voltage	V _{OL}	10 2011/7		-	0.15	V		
Output high short circuit pulsed current	I _{O+}	V _O =0 V, V _{IN} = VDD PW≤ 10 µs	2.0	2.5	-	А		
Output low short circuit pulsed current	I _{O-}	V _O =15 V, V _{IN} = 0 PW≤10 µs	2.0	2.5	-	А		



POWER SUPPLY							
Quiescent VBS supply current	I _{QBS}		-	45	100	μA	
Quiescent VCC supply current	I _{QCC}	VIN = 0 V or VDD	-	500	700	μA	
Quiescent VDD supply current	I_{QDD}		-	-	150	μA	
Offset supply leakage current	I _{LK}	VB=VS=600V	-	-	50	μA	
VCC and VBS supply under voltage positive going threshold	V _{BSUV+}		7.5	8.6	9.7	V	
VCC and VBS supply under voltage negative going threshold	$V_{\text{BSUV-}}$		7.0	8.1	9.2	V	
VCC and VBS supply under-voltage lockout hysteresis	V_{BSHY}		-	0.5	-	V	
SWITCHING CHARACTERISTIC	s						
Turn-on Rise Time	t _R		-	18	30	ns	
Turn-off Fall Time	t _F		-	13	20	ns	
Turn-On Propagation Delay	ton	C _L =1000pF,	-	128	150	ns	
Turn-Off Propagation Delay	t _{off}	See Figure 5, 6, 7, 8	-	124	150	ns	
Shutdown Propagation Delay	t _{sd}		-	120	150	ns	
Delay matching, turn-on/off	МТ		-	10	-	ns	



3. Application Information

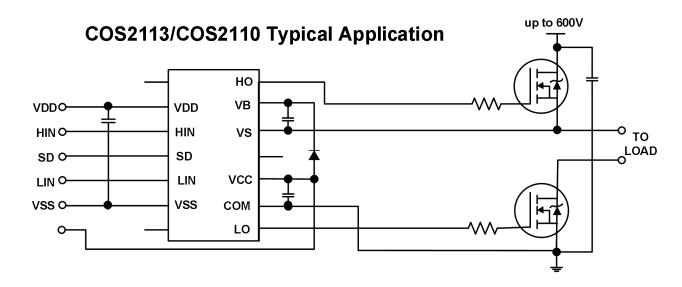


Figure 3. Typical Application

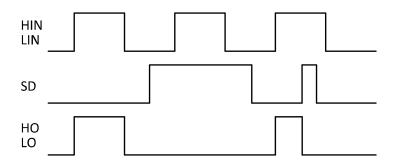


Figure 4. Input/Output Timing Diagram



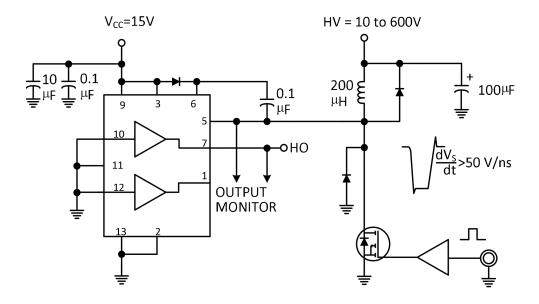


Figure 5. Floating Supply Voltage Transient Test Circuit

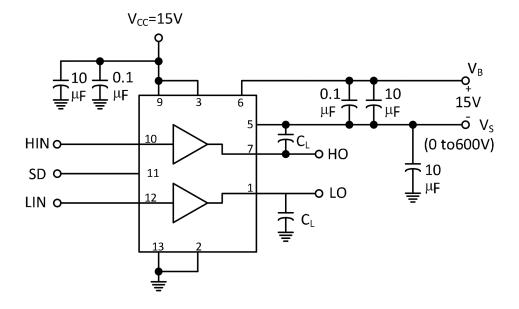


Figure 6. Switching Time Test Circuit



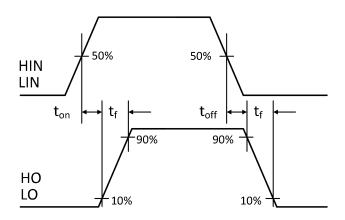


Figure 7. Switching Time Waveform Definition

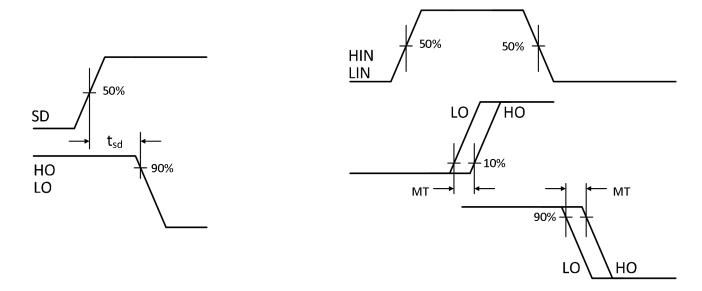


Figure 8. Shutdown Waveform Definition

Figure 9. Delay Waveform Definition

4. Ordering Information

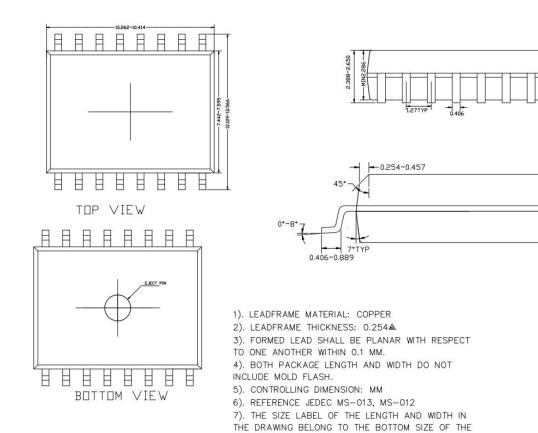
Model	Order Number	Package	Package Option	Marking Information
COS2113	COS2113STRPBF	WSOP-16	Tape and Reel, 1000	COS2113
COS2110	COS2113PBF	DIP-14	Tube 25	COS2113

€0.254TYP



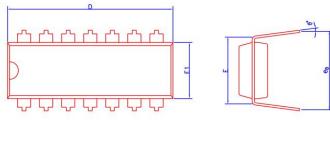
5. Package Information

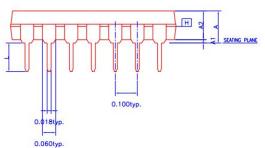
5.1 WSOP16 (Package Outline Dimensions)



PACKAGE.

5.2 DIP14 (Package Outline Dimensions)





SYMBOLS	MIN.	NOR.	MAX.
Α	-		0.210
A1	0.015	<u> </u>	ı
A2	0.125	0.130	0.135
D	0.735	0.750	0.775
E		0.300 BSC	
E1	0.245	0.250	0.255
L	0.115	0.130	0.150
e _B	0.335	0.355	0.375
θ°	0	7	15

UNIT : INCH

单击下面可查看定价,库存,交付和生命周期等信息

>>COSINE(科山芯创)